

EAST Search History

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|-------|---|---|------------------|---------|------------------|
| S166 | 13944 | 455/131.232.1,255,313,323,333,334.ccls. 438/151,163,585,586.ccls. 257/347,401,499,500,501,508,517,518,520,901.ccls. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/03/19 16:03 |
| S167 | 1894 | semiconductor with (differential near2 circuit) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/03/19 16:04 |
| S168 | 22026 | substrate same (gate adj electrode) same (drain adj electrode) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/03/19 16:08 |
| S169 | 12264 | substrate same (gate adj electrode) same (drain adj electrode) same semiconductor | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/03/19 16:09 |
| S170 | 534 | (gate adj electrode) with (drain adj electrode) with (resistance resistor) with semiconductor | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/03/19 16:09 |
| S171 | 7 | S167 and S170 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/03/19 16:13 |
| S172 | 9 | semiconductor adj differential adj circuit | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/03/19 16:15 |
| S173 | 27 | S166 and S170 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/03/19 17:06 |

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|-------|------|---|--------------------|------------------|---------|------------------|
| L1 | 0 | (semiconductor with (differential adj circuit) with substrate with ("same" near2 (resistance resistor)) with ((collector base) (drain with gate))).clm. | US-PGPUB; USPAT | OR | ON | 2006/03/19 17:30 |
| L2 | 0 | (semiconductor with (differential adj circuit) with substrate with ("same" near2 (resistance resistor))).clm. | US-PGPUB; USPAT | OR | ON | 2006/03/19 17:31 |